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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: Nobuhiko HAYASHI et al.

Group Art Unit: 2826

Serial No.: 09/898,043

Examiner: Johannes P. Mondt

Filed: July 5, 2001

P.T.O. Confirmation No.: 2566

FOR: NITRIDE-BASED SEMICONDUCTOR LIGHT EMITTING DEVICE AND NITRIDE
BASED SEMICONDUCTOR LASER DEVICE (as herein amended)

AMENDMENT UNDER 37 C.F.R. §1.111

Commissioner for Patents
Washington, D.C. 20231

Date: July 29, 2002

Sir:

In response to the Office Action dated February 27, 2002, please amend the above-identified
application as follows:

IN THE TITLE OF THE INVENTION:

Please amend the title to:

a1
NITRIDE-BASED SEMICONDUCTOR LIGHT EMITTING DEVICE AND NITRIDE
BASED SEMICONDUCTOR LASER DEVICE

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TECHNOLOGY CENTER 2800

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Adjustment date: 07/16/2003 ELKUDAYI
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